



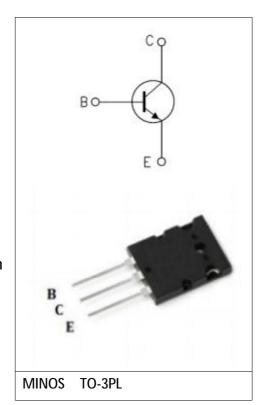
Minos High Power Products

NPN TRANSISTORS

Features:

- Power Amplifier Applications
- Complementary to 2SA1943
- High collector voltage:VCEO=230V (min)
- Recommended for 100-W high-fidelity audio frequency amplifier Output stage

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Absolute Maximum Ratings(Tc=25 °C):

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V CBO	230	V
Collector-emitter voltage		V CEO	230	V
Emitter-base voltage		V EBO	7	V
Collector current		l c	17	Α
Base current		lв	3	Α
Collector power dissipation	Tc=25°C	Pc	180	W
Junction temperature		Tj	150	$^{\circ}$
Storage temperature range		Тѕтс	-55~150	$^{\circ}$



2SC5200



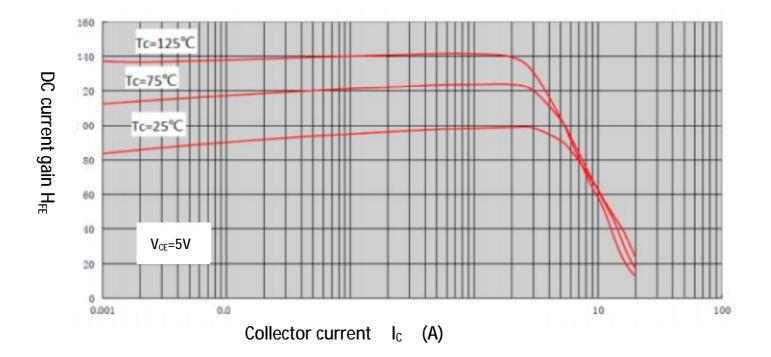
Electrical CharacteristicsTc= (25 °C):

Characteristics	Symbol	Test Condition		Min	Тур	Max	Unit
Collector cut-off current	СВО	VcB=230V;	I _E =0			500	uA
Emitter cut-off current	ЕВО	VEB=7V;	$I_c=0$			500	uA
Dc current gain	hfe	Ic=5A;	V _{CE} =4V;	70		140	
Collector-emitter saturation voltage	Vce(sat)	Ic=4A;	I _B =0.4A			0.5	V
Transition frequency	f⊤	Vce=10V;	Ice=500mA ;f=1MHZ		58		MHZ

Symbol	Paramter	Тур	Units
R _{0JC}	Junction-to-Case	0.68	°C/W

TYPICAL CHARACTERISTICS

H_{FE}--I_C



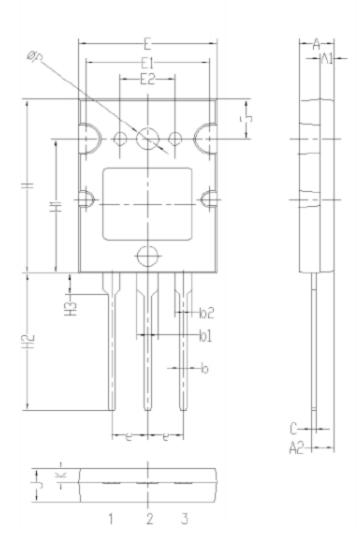


2SC5200



Package Information

TO-3PL PACKAGE



	¥俭: mm		
	MIN	NOM	MAX
Α	4.8	5	5.2
A'	1.8	2	2.2
A2	3	3.2	3.4
b	8.0	1	1.2
b1	2.8	3	3.2
b2	2.3	2.5	2.7
С	0.4	0.6	0.8
е	5.25	5.45	5.65
E	19.8	20	20.2
E1	17.8	18	18.2
E2	7.8	8	8.2
Н	25.8	26	26.2
H1	19.8	20	20.2
H2	20	20.5	21
H3	3.05	3.25	3.45
G	5.8	6	6.2
ØP	3.1	3.3	3.5
J	4.8	5	5.2
K	1.8	2	2.2